



Transient Voltage Suppressors for ESD Protection

DESCRIPTION

The SESDU5V0WB is designed to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time provide best in class protection on designs that are exposed to ESD. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space is at a premium.

FEATURES

- Stand-off Voltage: 5 V
- Low Leakage
- Response Time is Typically < 1 ns
- ESD Rating of Class 3 (> 12 kV) Per Human Body Model
- IEC61000-4-2 Level 4 ESD Protection
- These are Pb-Free Devices
- **Pb-Free package is available**
 - RoHS product for packing code suffix "G"
 - Halogen free product for packing code suffix "H"
- Moisture Sensitivity Level 1

WBFBP-02C

(1.0×0.6×0.5)
unit: mm



Maximum Ratings @T_a=25°C

Parameter	Symbol	Limit	Unit
IEC61000-4-2(ESD) Air/ Contact		± 15	kV
ESD voltage Per Human Body Model Per Machine Model		12	kV
		400	V
Total power dissipation on FR-5 board (Note 1)	P _D	100	mW
Thermal resistance junction-to-ambient	R _{θJA}	1250	°C/W
Lead solder temperature – maximum (10 second duration)	T _L	260	°C
Junction and storage temperature range	T _j , T _{stg}	-55 ~ +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only.

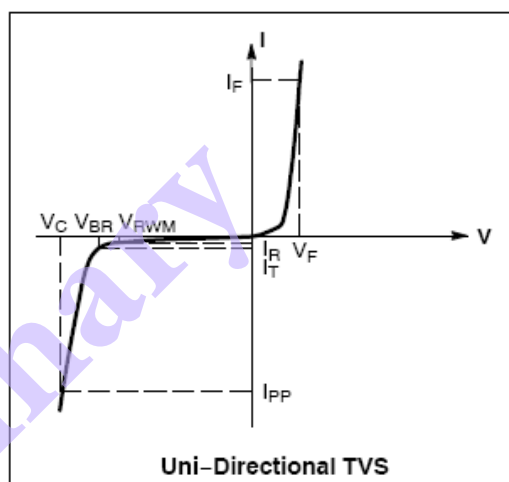
Functional operation above the Recommended. Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-5 = 1.0 x 0.75 x 0.62 in.

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ELECTRICAL CHARACTERISTICS (T_a = 25°C unless otherwise noted)

Symbol	Parameter
I _{PP}	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @ I _{PP}
V _{RWM}	Working Peak Reverse Voltage
I _R	Maximum Reverse Leakage Current @ V _{RWM}
V _{BR}	Breakdown Voltage @ I _T
I _T	Test Current
I _F	Forward Current
V _F	Forward Voltage @ I _F
P _{pk}	Peak Power Dissipation
C	Max. Capacitance @V _R =0 and f =1MHz



ELECTRICAL CHARACTERISTICS (T_a = 25°C unless otherwise noted)

Device*	Device Marking	V _{RWM} (V)	I _R (μA) @ V _{RWM}	V _{BR} (V) @ I _T (Note 2)		I _T (mA)	MAX I _{PP} (A)	V _C (V) @Max I _{PP}	C (pF)@ V _R =0V,f=1MHz
		Max	Max	Min	Max	-	-	Max	Typ
SESDU5V0WB	AE	5	1	5.4	9.4	1	1	10	0.5

*Other voltages available upon request.

2. V_{BR} is measured with a pulse test current I_T at an ambient temperature of 25°C.



Ordering Information:

Device PN	Packing
SESDU5V0WB -T ⁽¹⁾ G ⁽²⁾ -WS	Tape&Reel: 10 Kpcs/Reel

Note: (1) Packing code, Tape & Reel

(2) RoHS product for packing code suffix "G" ; Halogen free product for packing code suffix "H"

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